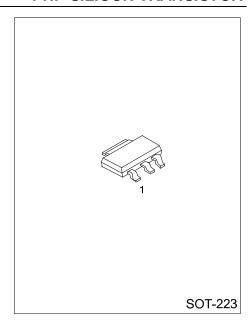
UP1855

PNP SILICON TRANSISTOR

HIGH CURRENT TRANSISTOR

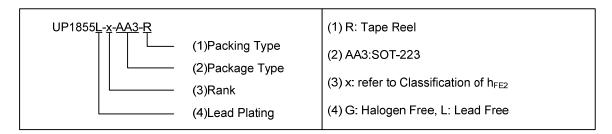
■ FEATURES

- * High current switching
- * Low $V_{\text{CE(SAT)}}$
- * High h_{FE}



■ ORDERING INFORMATION

Ordering Number		Doolsogo	Pin <i>i</i>	Assignr	Dooking		
Lead Free	Halogen Free	Package	1	2	3	Packing	
UP1855L-x-AA3-R	UP1855G-x-AA3-R	SOT-223	В	С	E	Tape Reel	



www.unisonic.com.tw 1 of 4

■ ABSOLUATE MAXIUM RATINGS (T_a = 25°C)

PARAMETER	SYMBOL	RATINGS	UNIT
Collector-Base Voltage	V_{CBO}	-180	V
Collector-Emitter Voltage	V_{CEO}	-140	V
Emitter-Base Voltage	V_{EBO}	-6	V
Peak Pulse Current	I _{CM}	-10	Α
Continuous Collector Current	Ic	-4	Α
Power Dissipation (T _a = 25°C) (Note 2)	P_D	3	W
Junction Temperature	TJ	+150	°C
Storage Temperature	T _{STG}	-40 ~ +150	°C

- Note: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.
 - 2. The power which can be dissipated assuming the device is mounted in a typical manner on a P.C.B. with copper equal to 4 square inch minimum

■ **ELECTRICAL CHARACTERISTICS** (T_a= 25°C, unless otherwise specified)

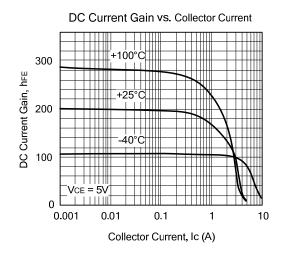
PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Collector-Base Breakdown Voltage	BV_{CBO}	$I_{C} = -100 \mu A$	-180	-210		V
Collector-Emitter Breakdown Voltage	BV_CEO	$I_C = -10 \text{mA}$	-140	-170		V
Emitter-Base Breakdown Voltage	BV_{EBO}	I _E = -100μA (Note)	-6	-8		V
Collector Cut-off Current	I _{CBO}	V _{CB} =-150V			-50	nA
		V _{CB} =-150V, T _a =100°C			-1	μΑ
Emitter Cut-off Current	I _{EBO}	V _{EB} =-6V			-10	nA
Collector-Emitter Saturation Voltage	V _{CE} (SAT)	I _C =-100mA, I _B =-5mA (Note)		-30	-60	mV
		I _C =-500mA, I _B =-50mA (Note)		-70	-120	mV
		I _C =-1A, I _B =-100mA (Note)		-110	-150	mV
		I _C =-3A, I _B =-300mA (Note)		-275	-550	mV
Base-Emitter Saturation Voltage	V _{BE (SAT)}	I _C =-3A, I _B =-300mA (Note)		-970	-1110	mV
Base-Emitter Turn-On Voltage	V _{BE (ON)}	V _{CE} =-5V , I _C =-3A (Note)		-830	-950	mV
DC Current Gain	h _{FE1}	V _{CE} =-5V , I _C =-10mA (Note)	100	200		
	h _{FE2}	V _{CE} =-5V , I _C =-1A (Note)	100		300	
	h _{FE3}	V _{CE} =-5V , I _C =-3A (Note)	28	140		
	h_{FE4}	V _{CE} =-5V , I _C =-10A (Note)		10		
Transition Frequency	f⊤	V _{CE} =-10V , I _C =-100mA, f=50MHz		110		MHz
Output Capacitance	Cob	V _{CB} =-20V, f=1MHz		40		pF
Switching Times	t _{ON}	V _{CC} =-50V, I _C =-1A		68		ns
	t _{OFF}	I _{B1} =-100mA, I _{B2} =100mA		1030		ns

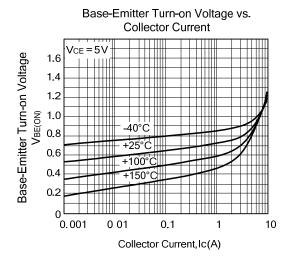
Note: Pulse test: $t_P \le 300\mu s$, Duty cycle $\le 2\%$

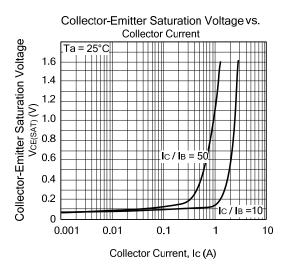
■ CLASSIFICATION OF h_{FE3}

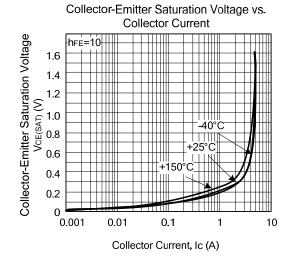
RANK	А	В
RANGE	28~75	75(MIN.)

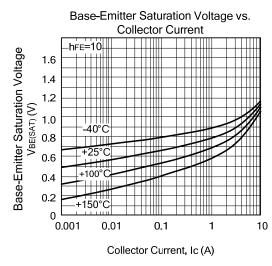
■ TYPICAL CHARACTERISTICS

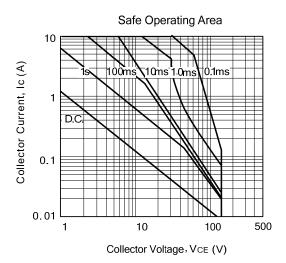












UTC assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all UTC products described or contained herein. UTC products are not designed for use in life support appliances, devices or systems where malfunction of these products can be reasonably expected to result in personal injury. Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner. The information presented in this document does not form part of any quotation or contract, is believed to be accurate and reliable and may be changed without notice.